NSN 5961-01-084-8901

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View Online at https://aerobasegroup.com/nsn/5961-01-084-8901 **Inclosure Material:** Metal **Overall Length:** Between 0.250 inches and 0.450 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -80.0 breakdown voltage, collector to emitter, sustained **Current Rating Per Characteristic:** 0.30 milliamperes zero-gate-voltage source current outside diameter **Power Rating Per Characteristic:** 70.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** 20 mhz; junction pattern arrangement: pnp **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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